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1,*n*-Alkanedithiol (*n* = 2, 4, 6, 8, 10) Self-Assembled Monolayers on Au(111): Electrochemical and Theoretical Approach

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The structures of 1,*n*-alkanedithiol (*n* = 2, 4, 6, 8, 10) self-assembled monolayers (SAMs) on a Au(111) substrate were investigated by electrochemical measurements and theoretical calculations. The results of the experimental techniques indicated that the dithiols, except *n* = 2, showed an upright molecular structure in the SAMs, in which alkanedithiols were bound to the Au surface *via* only one thiol functionality and the other one faced up to the air. The results also suggested that the formed dithiol SAMs were densely packed and highly oriented. Except ethanedithiol, which was thought to form a bilayer, the reductive desorption peak potentials of 1,*n*-alkanedithiol (*n* = 4, 6, 8, 10) SAMs were more negative than those of the corresponding monothiol ones in 0.1 M KOH solutions. This illustrates that the dithiol SAMs had higher stability than the corresponding monothiol ones. The major part of the high stability may be attributed to the van der Waals interaction among the sulfur atoms on top of the dithiol SAMs. The molecular modeling calculation showed that the structures of dithiol SAMs were similar to those of the corresponding monothiol SAMs and that all the dithiol SAMs, except ethanedithiol, were more stable than the corresponding monothiol SAMs. The calculated energy differences between dithiol and monothiol SAMs decreased with the increment of alkyl-chain length.

Key Words: Alkanedithiol, Alkanethiol, Self-assembled monolayer, Au(111), Electrochemistry

Introduction

Self-assembled monolayers (SAMs) of organic thiols on gold have been extensively studied in past decades.^{1,2} They provide a good molecular candidate to be used in many application areas as well as a highly reproducible model system for understanding organic interface. The SAMs with ω -functional groups have been of particular interest.¹⁻⁵⁷ Those functionalities on top of SAMs mainly control the surface properties of the organic film and provide the possibility to connect with other functional units. Among them, thiol-terminated surface, with their high affinity to metals, can serve as templates for the formation of metal film or metal wires at SAM-ambient interface by preventing the diffusion of metal into SAMs and formation of a short circuit.^{3-7,14-17,22-25} It can also be used as building blocks for constructing multilayers.²⁷⁻³⁵ The most suitable constituent for the formation of thiol terminated SAMs is dithiol. Dithiol SAMs have been utilized to make nano-devices, measurements of electricity transport and multilayer formation.^{3-7,14-17,22-38} But most of those studies only focus on the electronic properties of dithiol SAMs. Compared to the well studied monothiolate SAMs, there are relatively less reports focused on the structure and growth of dithiol SAMs.

Due to the two thiol groups existing in the dithiol molecule, the possibility to form a bridge or loop-like structure, in which a dithiol molecule adsorbed flat on a Au substrate *via* two sulfur atoms, can not be ruled out in the formation of dithiol SAMs. For example, 1,6-hexanedithiol was found to be adsorbed flat on Au revealing a parallel molecular orientation from the gas phase.³⁹ SAMs of 2-monoalkylpropane-1,3-dithiol

derivatives, $\text{CH}_3(\text{CH}_2)_n\text{CH}[\text{CH}_2\text{SH}]_2$, were also reported to bond Au with the two thiol groups from a solution.⁴⁰ On silver, dithiol molecules are usually adsorbed as dithiolates by forming two Ag-S bonds.⁴¹⁻⁴⁴ This looping construction will impede the formation of thiol-terminated SAMs and, further more, inhibit its application in molecular electronics.

On the other hand, other studies showed that alkanedithiol, as well as aromatic dithiol, adsorbed on gold surface from solution as monothiolate *via* only one thiol functionality.^{22-38,41,45-55} In this upright molecular structure, the unbound thiol group is pendent with respect to the Au substrate and serves as the platform for the applications, such as the preparation of copper (I)-dithiol or CdS nanoparticle-dithiol multilayer thin films, the formation of multilayer through disulfide linkage spontaneously or electrochemically, the measurement of electron transfer through single molecule or the construction of metal-molecule-metal sandwich structure.^{3,22-27,30-38} However, the quality of those thiol terminated surface has been debated. Loose pack, ill-defined dithiol adlayers, which were prepared by simple immersion of gold substrate into a solution of dithiol, were reported.^{52,53} In order to obtain compact thiol-terminated dithiol SAMs, different formation methods were proposed including protection of one thiol-group as thiolacetate and the following regeneration of SH on top of the formed dithiol SAMs and using organodithiols with more rigid backbones.^{25,52,53} The control of formation condition such as using different solvent, removal of oxygen from SAMs formation solution were also suggested.^{22-25,30,31,41,47-51,54-57} Formation of disulfide bond through the terminated free thiols on top of dithiol SAMs were reported as well.^{32-35,48,49} Those interlayer and intralayer

disulfide linkage will result in the formation of multilayer and rearrangement of molecular configuration of dithiol molecules in the SAM, respectively.

In this study, a series of densely packed, looping structure free, thiol-terminated alkanedithiol SAMs with higher stability than those of monothiolate SAMs were prepared. Those thiol-terminated dithiol SAMs were examined by electrochemical measurements. As a comparison, the corresponding monothiolate SAMs were also investigated. With the aid of theoretical calculation, the structure of thiol-terminated alkanedithiol SAMs was determined. Our goal was to clarify some previous contradiction and to provide information of the structure, quality and stability of alkanedithiol SAMs on Au(111) substrate. The possibility of the formation of disulfide was also discussed.

Experimental Section

Materials. All chemicals were of the best quality available commercially and used as received. Water was purified using a Milli-Q purification system (Millipore). Ultrapure Ar gas (99.9995%) was purchased from Air Water.

A Au(111) single crystal, which was used in electrochemical measurements, was prepared from a gold wire (99.999% pure, Tanaka Precious Metal) by the Clavilier method and was then cut and mechanically polished.⁵⁸ The real surface area of the Au(111) single crystal electrode was estimated from the cathodic current corresponding to the reduction of Au oxide to be 0.078 cm².

Electrochemical Measurements. Electrochemical measurements were performed in a three-compartment electrochemical cell using an EG&G 283A potentiostat. The electrode potential was referred to a Ag/AgCl (saturated NaCl) electrode and a Pt wire was used as a counter electrode. The electrolyte solution was deaerated by bubbling Ar gas for at least 30 min before each experiment.

Ellipsometry. Ellipsometry measurements were performed using a SOPRA, GES-5 ellipsometer in a wavelength region of 300 - 800 nm with an incident angle upon the sample of 75° at Hokkaido University. A software program (WINELLI) was employed to determine the monolayer thickness. The refractive index of the SAMs was assumed to be 1.45.²

SAMs Preparation. The monothiols (C2SH, C4SH, C6SH, C8SH and C10SH) were self-assembled on Au(111) surface by simple immersion of Au(111) substrate into an ethanolic solution containing 1 mM of respective alkanethiol for 12 hours. The dithiol (C2S2, C4S2, C6S2, C8S2 and C10S2) SAMs were prepared by immersing the Au substrate in an ethanol solution of 1, *n*-alkanedithiol (*n* = 2, 4, 6, 8, 10) with a concentration of 1 mM for 2 or 3 hours. The dithiol solutions were saturated with Ar before the incubation and were kept under Ar atmosphere and in the dark during the formation of dithiol SAMs.

Theoretical Method and Molecular Modeling. Molecular modeling calculations for SAMs and single thiol molecule bound to gold surface were performed with a HyperChem (Hypercube, Inc) software program on a PC with an Intel Pentium D 2.66 GHz microprocessor.⁵⁹

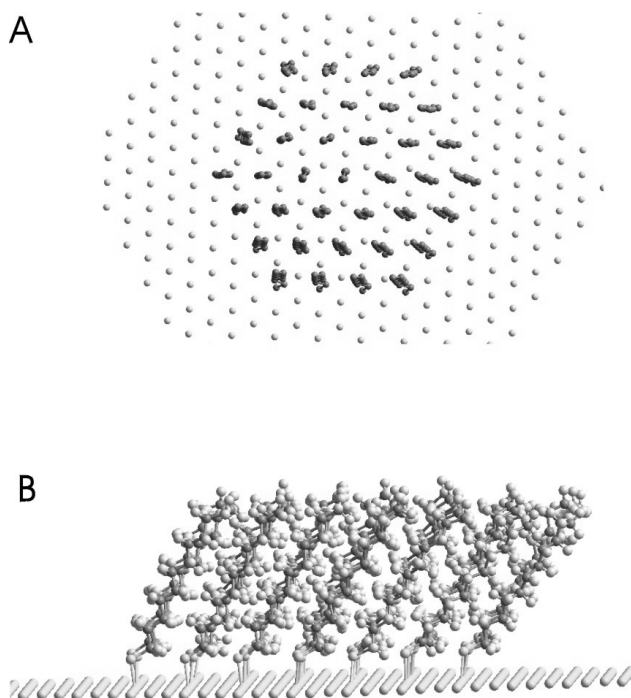


Figure 1. Simulated structure of mono/dithiol SAMs on a Au(111) substrate surface with a fixed distance between two molecules of 5 Å (A: top view, B: side view).

The initial structure of each monothiol (C2SH, C4SH, C6SH, C8SH and C10SH) and dithiol (C2S2, C4S2, C6S2, C8S2 and C10S2) molecules were obtained by a model builder. The stable structure was obtained through 'geometry optimization' using ab initio quantum mechanical calculation with a '6-31G*' basis set. The atomic charges for each atom in the molecule were obtained and used to calculate the electrostatic term of potential energy in molecular mechanics.

The Au(111) surface coordinates were obtained from 'crystal builder'⁶⁰ and achieved manually by rotating coordinates of the crystal to find the cross section of Au(111). The monothiol and dithiol molecules were then deposited on Au(111) surface with a distance of 5 Å as shown in Figure 1. The SAMs structure contained 37 thiol or dithiol molecules. As shown in Fig. 1a, the center molecule was encircled by 6, 12 and 18 molecules as 1st, 2nd and 3rd layer of surrounding molecules, respectively. In this configuration, the center molecule was used as a representative of molecules in SAMs.

MM+ force field, which is an extension of MM2, developed by Allinger and co-workers to represent the potential energy was used in this study.⁶¹

The structures obtained through 'geometry optimization' are not optimum geometry, because the potential energy surfaces are too complex for simple geometry optimization to find the real optimum structure. A molecular dynamics simulation for more than 100 ps depending on the size of molecule with keeping the coordinates of all Au atoms was performed. Then a 2nd molecular dynamics simulation for 1 ns was performed from the starting point with the final structure of the previous simulation. The constant temperature of 300 K was used in the simulation.

The calculated angles of the monothiol and dithiol molecules in the SAM with respect to the surface normal of Au (111) substrate were compared with the experimental ones and the validity of present calculation was justified.

One of the purposes of this calculation was to determine the stabilization energy of thiol molecules in SAMs due to their intermolecular interactions. To achieve this, the energy of center molecule in each SAM was used. 100 snapshots with the same intervals from the result of 1 ns molecular dynamics for every SAM on Au(111) were collected. The energy of each snapshot was calculated by performing 'single point' calculation.

Results and Discussion

Linear Sweep Voltammogram. The linear sweep voltammograms (LSV) of 1,*n*-alkanedithiol (*n* = 2, 4, 6, 8, 10) SAM on a Au(111) substrate were recorded in a 0.1 M KOH solution with a potential scan rate of 20 mV s⁻¹ as are shown in Figure 2a. As a comparison, the LSV of alkanethiol (C2SH to C10SH) were also recorded and are shown in Figure 2b. In Figure 2a, a series of sharp cathodic peaks corresponding to the reductive desorption of the C2S2, C4S2, C6S2, C8S2 and C10S2 SAM were observed at -0.885, -0.908, -0.970, -1.035, -1.105 V. The reductive peak potentials of dithiol SAMs were negatively shifted as alkyl chain length was increased from two to ten. This chain length dependent phenomenon was also found in the reductive desorption of alkanethiols in previous studies and was reproduced to be shown for comparison in Figure

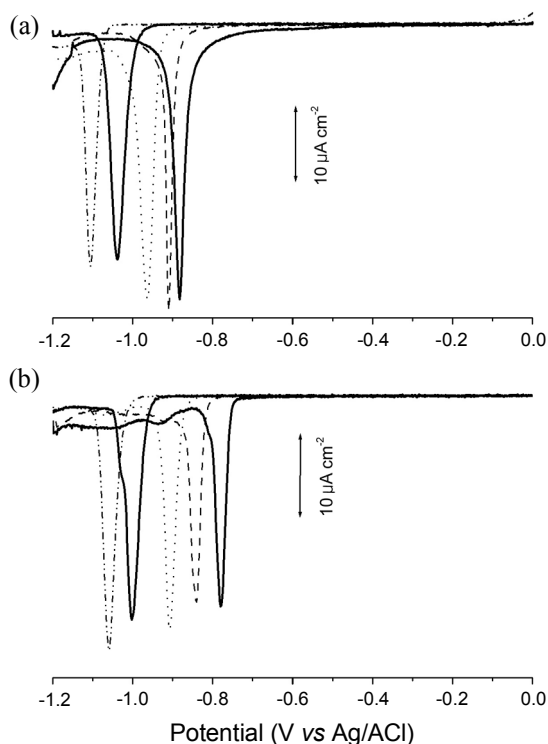


Figure 2. Linear sweep voltammograms of (a) 1, *n*-alkanedithiol (*n* = 2, 4, 6, 8, 10) and (b) alkanethiol (*n* = 2, 4, 6, 8, 10) SAM on a Au(111) electrode in 0.1 M KOH solution with potential scan rate of 20 mV s⁻¹.

2b.^{62,63} As demonstrated in prior work, there are several interactions involved in the organothiol SAMs on Au substrate, including S-Au interaction, chain-chain interaction, headgroup-headgroup and headgroup-environment interaction. The overall balance of those interactions governed the structure and stability of the SAMs. Increase of the chain length will increase the stability of the SAMs and, therefore, result in negatively shifting the peak potentials of the desorptive reduction. Notice that the reductive desorption peak potential of C2S2 was rather similar to that of the C4S2, implying some deviation from simple dithiol SAM formation such as a bilayer formation of C2S2. The formation of C2S2 bilayer was checked by the ellipsometry measurement. The measured ellipsometric thicknesses of C2S2 and C4S2 layers on a vacuum-evaporated Au substrate surface were found to be 0.65 ± 0.04 nm and 0.67 ± 0.03 nm, respectively. This suggests that a C2S2 bilayer was formed and the thickness of this bilayer was similar to that of C4S2 monolayer, which resulted in the similar reductive peak potential in the two samples. This observation is in agreement with the previous report, in which a bilayer will be formed on Au by C2S2 in an ethanolic solution even in its sub-monolayer coverage.⁴⁶ Other multilayers were not noticed with the experimental conditions of the dithiols investigated in this study, reflecting that formation of SAMs and multilayers is the sensitive function of the experimental variables of medium, concentration, impurities and immersion time among others.²⁷⁻³⁵

To clearly see the relationship between the reductive desorption peak potentials in different alkyl chain-length thiol and dithiol, the reductive peak potential and the peak potential difference between thiol and dithiol were plotted as a function of the number of carbons in those molecules and are shown in Figure 3 and 4, respectively. Figure 3 shows that, the reductive peak potentials of dithiol SAMs were always more negative than those of the corresponding thiol SAMs, which indicates that the dithiol SAMs are more stable than the corresponding monothiol SAMs. As shown in Figure 4, the peak potential differences between the thiol and dithiol with the same chain length were greater than 50 mV, and had a trend of decrement with chain length increased. This negative shift in reduction

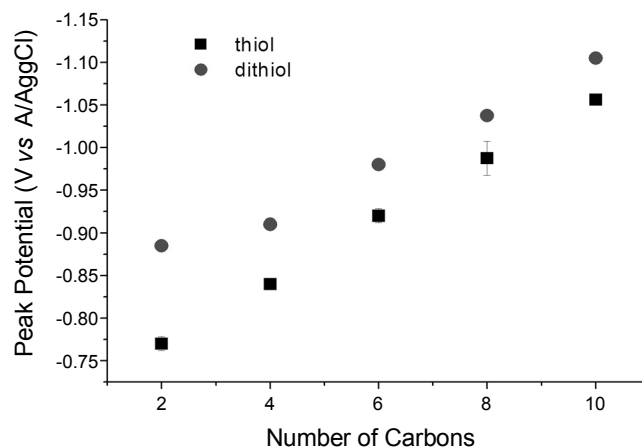


Figure 3. Dependence of reductive desorption peak potential of dithiol SAMs (circle) and monothiol SAMs (rectangle) on the number of carbon atoms in the molecules.

potential from alkanethiol to alkanedithiol SAMs can be attributed to the different headgroup-headgroup interaction in the two types of SAMs. The S-S interactions on dithiol SAMs are higher than that of $\text{CH}_3\text{-CH}_3$ on thiol SAMs and therefore, make the dithiol SAMs reductive peak position negatively shifted. It was surprising at first to observe the chain length dependence of the reductive potential shift between alkanethiol and alkanedithiol SAMs, since, for different chain length, the headgroup-headgroup interaction difference ($E_{\text{S-S}} - E_{\text{CH}_3\text{-CH}_3}$) would be the same and the chain length independence would be expected. The observed chain length dependent phenomenon can be explained by the change in the SAMs structure, the contribution of S-S interaction to the total energy of SAMs and the energy of S-S interaction itself followed with the change of alkyl chain length. It has been confirmed that the structure of alkanethiol SAMs, eg. tilt angle and tilt direction, will change with alkyl chain length.^{64,65} The similar observations were found in the dithiol SAMs investigated in the theoretical study (*vide infra*). The structure of dithiol SAMs will affect the S-S interaction energy. The increase in chain length will increase the energy of chain-chain interaction and, therefore, the relative contribution of S-S interaction to the total energy of dithiol SAMs will decrease upon increasing the alkyl chain length. Since the structure of SAMs were determined by the overall balance of the different energies contributing to the formation of the SAMs, the decrease of S-S interaction energy contribution will cause the SAMs structure change unfavored for the S-S interaction. This may result in the decrease of the contribution of the S-S interaction energy with chain length increased.

The charges associated with the reductive desorption of those dithiol SAMs were found in the range of $100 (\pm 5\%) \mu\text{C cm}^{-2}$ without double-layer charge correction, which is in good agreement with the value for the reductive desorption of alkanethiolate SAMs with saturated coverage of a $(\sqrt{3} \times \sqrt{3}) R 30^\circ$ structure formed on a Au(111) surface.^{62,63,66-68} It should be mentioned that this value consists of 70% of Faradaic charge for one-electron reduction of SAMs with saturated coverage of a $(\sqrt{3} \times \sqrt{3}) R 30^\circ$ structure and 30% of capacitive (non-Faradaic) charge.^{62,63,66-68} The fact that the constant charge corresponding to the full monolayer coverage of dithiol

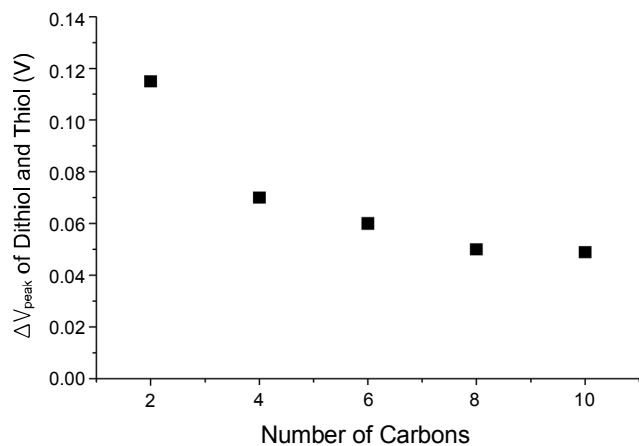


Figure 4. Plot of reductive desorption peak potential shift as a function of chain length.

S-Au was observed for a series of dithiols excludes the formation of looping structure in the dithiol SAMs investigated.

The above results are different from the previous study,⁴⁸ in which the reductive charge more than that of a full monolayer was observed. A partially formed intralayer disulfide bond on top of dithiol SAMs was proposed and the extra charge was suggested to be due to the dissociation of the disulfide bond. But this explanation cannot match with the fact that the bond energy of disulfide is higher than that of sulfur-Au bond, in which the breaking of S-Au bond and the dissociation of disulfide bond can not take place simultaneously and therefore, the charge corresponded to these two process will not mix together.^{1,2,69}

Theoretical Calculation. Molecular dynamics calculations for each SAMs were performed for 100 ps and 1 ns for 1st and 2nd simulation, respectively, at 300 K. The angles of the monothiol and dithiol molecules in each SAM were collected from their optimized structure after the 2nd molecular dynamics. The plots of population as a function of tilt angle of SAMs with different carbon numbers are shown in Figure 5. It shows that with increase of alkyl chain length, the tilt angles of molecules in SAMs slightly increased and most were around 20 ~ 35 degree. In the mean time, the molecular population peak became narrow and sharp, which indicates a relatively disordered SAM with shorter chain length and a highly

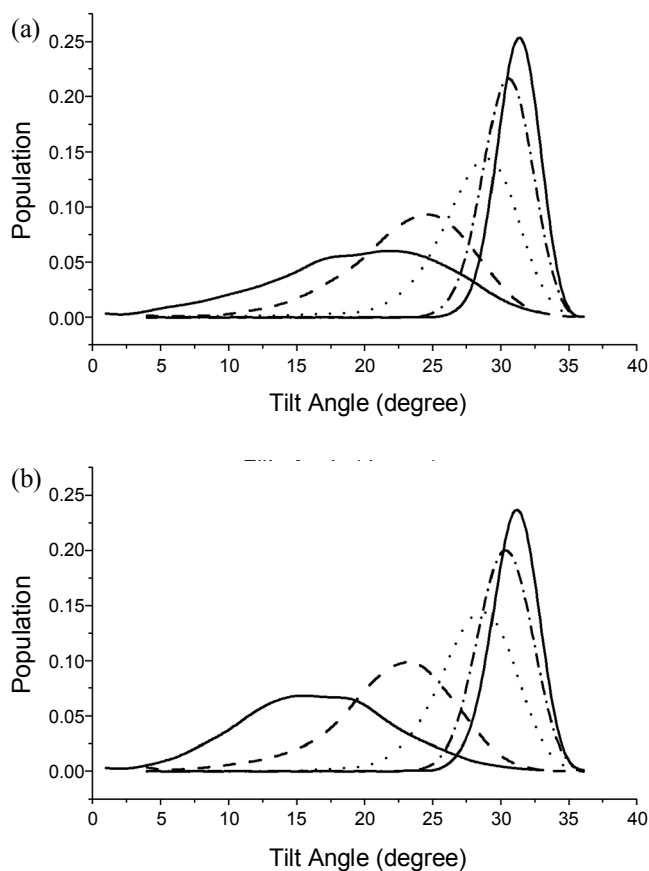


Figure 5. Plots of population versus tilt angle of simulated monothiol (a) and dithiol (b) molecules in the SAMs with different number of carbons; C2 (full line), C4 (dash line), C6 (dotted line), C8 (dash-dotted line), C10 (full line).

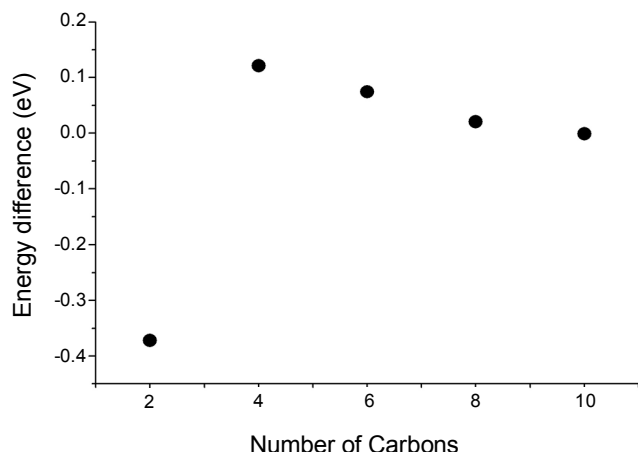


Figure 6. Calculated free energy differences between monothiol and dithiol SAMs as a function of alkyl chain length.

orientated SAM with longer chain. This agrees with the experimental observation that the SAMs of short alkanethiol were liquid-like and became solid crystalline-like when the chain length was increased.⁷⁰ It also agrees well with the fact that the tilt angle for the SAMs of longer alkylthiol is 30 degree.^{1,2,64} It is interesting to note that those optimized structures of dithiol SAMs, except ethanedithiol, are similar to those of corresponding monothiol ones, suggesting that the alkyl chain of dithiol molecule in SAMs has all *trans* conformation.

The potential energies of SAMs for monothiol and dithiol were obtained by calculating the potential energy of center molecule in the SAMs. The energy differences between monothiol and dithiol SAMs were plotted as a function of alkyl chain length in Figure 6. Similar to those experimental results shown in Figure 4, except ethanedithiol, the energy differences between monothiol and dithiol SAMs decrease with chain length increased. In case of the ethanedithiol SAM, it was found that its energy was even higher than that of ethanethiol SAM (1.19 eV and 0.82 eV for ethanedithiol and ethanethiol, respectively). This may be the reason that, due to their unstable structure, a monolayer of ethanedithiol can not be formed. Instead, a bilayer will be formed on Au by C2S2 even in its sub-monolayer coverage.⁴⁶

Conclusion

Densely packed and highly ordered 1,n-alkanedithiol ($n = 2, 4, 6, 8, 10$) SAMs with an upright molecular structure, in which all dithiol molecules were found to be bound to the substrate *via* the thiolate link from one of the thiol groups and the second one free at the SAM-ambient interface, were formed on a Au(111) substrate. A high stability of dithiol SAMs compared to their corresponding monothiol SAMs was confirmed by the observation of a negative reductive peak potential shift from monothiol SAMs to dithiol SAMs. The highly stabilized effect of S-S intralayer interaction on the thiol terminated dithiol SAMs surface was thought to be the main cause. The theoretical calculation demonstrated that the dithiol and monothiol SAMs have the similar structure. The

calculated free energies of mono and dithiol SAMs showed the same trend as observed by experimental means. Ethanedithiol was found to form a bilayer due to its unstable structure of monolayer.

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